



# Data Sheet

Customer:	
Part No:	CL-LDD56UHR-650-5mW
Sample No:	
Description:	Laser Diode
Item No:	

Customer					
Check	Inspection	Approval	Date		





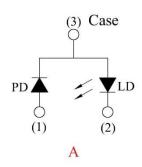
#### **Features**

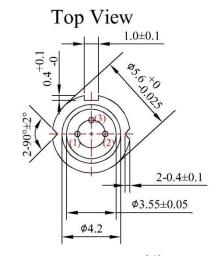
- 1. Low operating current
- 2. Standard optical power output : 5mW (CW)
- 3. TO-56 ( $\phi$  5.6mm) package, cap window without lens.
- 4. Built-in Photo Diode for monitoring laser power.

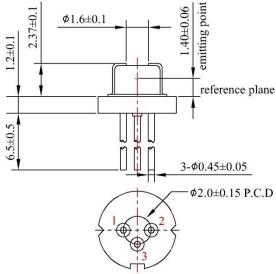
### Applications

- 1. Laser pointer
- 2. Bar code scanner
- 3. Medical
- 4. Rangefinder
- 5. Laser leveler

### **External dimensions(Unit:mm)**







**Bottom View** 





### Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit	
Optical Output (Tc=25°ℂ)	Po	5	mW	
LD Reverse Voltage (Tc=25°℃)	Vr_LD	2	V	
PD Reverse Voltage (Tc=25°℃)	Vr_PD	30	V	
Operating Temperature (Case)	Тор	-10~+70	$^{\circ}$	
Storage Temperature	Tstg	-40~+85	$^{\circ}$	

### **■ Electrical and Optical Characteristics**(Tc=25°C)

Parameter		Symbol	Condition	Min.	Тур.	Max.	Unit
Threshold Current		Ith	-	-	10	13	mA
Operating Current		Iop	Po=5mW	-	16	20	mA
Operating Voltage		Vop	Po=5mW	-	2.1	2.3	V
Slope Efficiency		η	Po=1.25-3.75mW	0.7	0.9	-	mW/mA
Monitor Current		Im	Po=5mW, V <sub>RD</sub> =5V	0.05	0.18	0.4	mA
Beam Divergence	Parallel	θ //	Po=5mW	5	8	12	deg.
(FWHM)	Perpendicular	$ heta$ $_{\perp}$	Po=5mW	30	36	42	deg.
Lasing Wavelength		λ	Po=5mW	640	650	660	nm

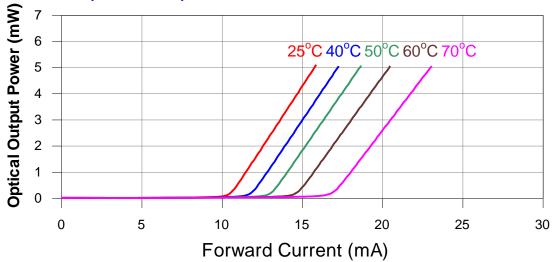
 $<sup>\</sup>circ$   $\theta_{\text{//}}$  and  $\theta_{\text{\perp}}$  are defined as the angle within which the intensity is 50% of the peak value.



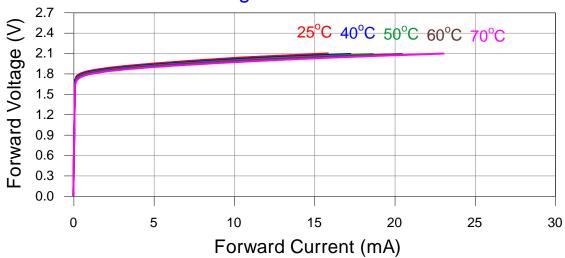


### Typical characteristic curves

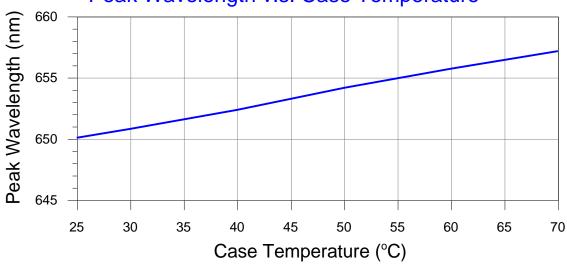
# Optical Output Power v.s. Forward Current



## Forward Voltage v.s. Forward Current

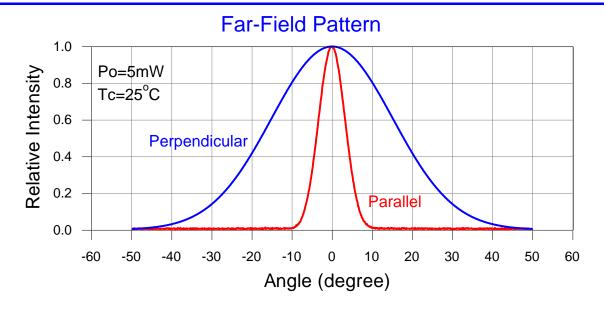


# Peak Wavelength v.s. Case Temperature

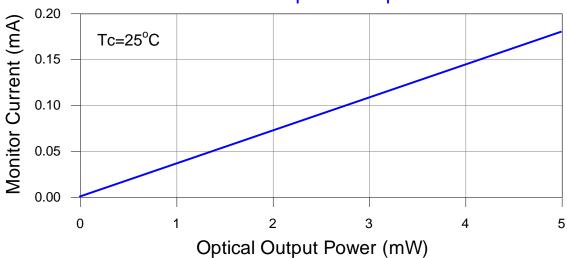




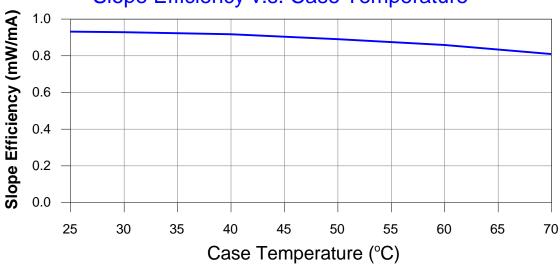




# Monitor Current v.s. Optical Output Power

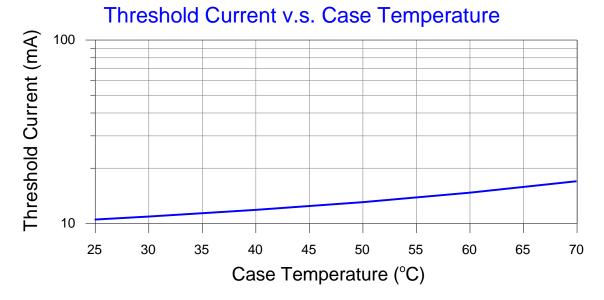


# Slope Efficiency v.s. Case Temperature









#### Precautions

#### **QUALITY ASSURANCE**

After any processing of laser chip or laser diode TO-CAN (LD) by the customer, the performance, yield and reliability of the product, in which the chip or LD is applied, are subject to change due to customer's handling, assembly, testing, and processing. Because laser chip and LD are strongly affected by environmental conditions, physical stress, and chemical stresses imposed by customer that are not in Ciellight Corp. control and hence no guarantee on the characteristics and the reliability at all after the shipment. Also, CL does not have any responsibility for field failures in a customer product. When attaching a heat sink to laser chip or LD, be careful not to apply excessive force to the device in the process.

#### **SAFETY PRECAUTIONS**

Although Ciellight Corp. keeps improving quality and reliability of its laser chip and laser diode TO-CAN (LD), semiconductor devices in general can malfunction or fail due to their intrinsic characteristics. Hence, it is required that the customer 's products are designed with full regard to safety by incorporating the redundancy, fire prevention, error prevention so that any problems or error with CL laser chip or LD does not cause any accidents resulting in injury, death, fire, property damage, economic damage, or environmental damage. In case customer wants to use CL laser chip or LD in the systems requiring high safety, customer is requested to confirm safety of entire systems with customer's own testing.

#### SPECIFICATIONS ARE SUBJECT TO CHANGE WITHOUT NOTICE.

The information provided by Ciellight Corp., including but not limited to technical specifications, recommendations, and application notes relating to laser chip or laser diode TO-CAN (LD) is believed to be reliable and accurate and is subject to change without notice. CL reserves the right to change its assembly, test, design, form, specification, control, or function without notice.